Investigation of grain boundary segregation in acceptor and donor doped strontium titanate


Abstract

Grain boundary segregation in electronic ceramics is often responsible for dictating the grain boundary properties, which in turn dictate the macroscopic electronic properties of the material. Consequently, it is important to understand the nature of segregation phenomena in these materials. Here we present results from a combination of diverse analytical techniques used to investigate the character of grain boundary segregation in acceptor (Fe, Mn) and donor (Nb) doped strontium titanate. X-ray emission spectroscopy (XES) and electron energy loss spectroscopy (EELS) analysis consistently show segregation of both acceptor (Fe, and Mn) and donor (Nb) dopant species to the grain boundaries. Within the spatial resolution of the techniques, the segregation profiles for these dopants are found to be limited to less than 5 nm about the grain boundaries. Furthermore secondary ion mass spectroscopy shows that the segregation is ubiquitous throughout the samples, and not limited to selected grain boundaries.

Keywords: Grain boundary segregation; Strontium titanate; EELS; XES; SIMS

1. Introduction

Electronic ceramics have become increasingly important as is evidenced by the rapid growth of the electronic ceramics industry, with multi-billion dollar annual sales. The technological importance of these materials depends on the tailoring of the ceramic to obtain the desired electronic properties which can then be exploited to produce a wide array of electronic products. The character of the macroscopic electronic properties of these electronic ceramics, such as varistors, PTCR thermistors, or grain boundary layer capacitors, are often controlled by electrically active grain boundaries. The grain boundary properties can be tailored by varying processing conditions, such as thermal treatments and furnace environments, as well as by intentional addition of dopants to the material. Consequently, it is critical to understand the nature of the grain boundaries to further refine processing treatments.

Grain boundary segregation plays a critical role in altering the local chemistry and, hence, electronic structure, of the grain boundary region. Kingery [1,2] has discussed the effects of grain boundary structure and characteristics and solute segregation in ceramic materials. Yan et al. [3] also have investigated the nature of solute segregation in ceramics considering elastic, electrostatic, and dipole interactions as the major driving forces for solute segregation in ceramics. Frenkel [4] posited the creation of space
charge regions about line and planar defects in ionic materials as a consequence of differences in the point defect formation energies of different species. At equilibrium, the difference in formation energies would be manifested as differences in defect populations. In the case of ceramic materials, migration of charged defects to the grain boundaries would result in the formation of space charge regions at the boundaries due to the different concentrations of oppositely charged defect species.

Chiang and Takagi [5] (using XES) and Desu and Payne [6] (using XES, AES and theoretical calculations) have studied the nature of solute segregation in SrTiO$_3$ and BaTiO$_3$ acceptor- and donor-doped samples which were sintered in air or reducing atmospheres. Both groups observed acceptor segregation to the grain boundaries, however Desu and Payne also observed appreciable donor segregation to the grain boundaries while Chiang and Takagi did not. Both groups also observed host cation non-stoichiometry across the interface.

In this paper, we present the results of our investigations of acceptor and donor segregation in both polycrystals and bicrystals of SrTiO$_3$. We have applied a number of analytical electron- and ion-beam techniques, to understand the chemical segregation behavior at grain boundaries in doped SrTiO$_3$. X-ray Emission Spectroscopy (XES) and Electron Energy Loss Spectroscopy (EELS) analysis of grain boundaries were conducted to determine whether there is acceptor and donor solute segregation and, furthermore, what form such a segregation profile would possess. Secondary Ion Mass Spectroscopy (SIMS) [7] was also employed to ensure that the analytical microscopy results were representative of the sample and not simply limited to a few “choice” grain boundaries.

2. Experimental

The Fe doped strontium titanate polycrystalline specimen used in this study were prepared by standard mixed oxide techniques and sintered in a flowing oxygen furnace producing a fine (≤ 2.5 μm) grained material [8]. The nominal composition of the Fe doped SrTiO$_3$ is Sr$_{9.00}$Ti$_{0.08}$Fe$_{0.02}$O$_3$. In addition to the bulk Fe dopant, a grain boundary specific dopant, Mn, was added via a second firing treat-

ment to some of the Fe doped specimen.

Donor (Nb)-doped bicrystals of SrTiO$_3$ were obtained from a commercial vendor (Shinkosha Co. Ltd., Japan). These bicrystals are grown from the melt from oriented seed crystals. The bulk doping level of Nb is 0.5 wt.%. Through electron diffraction techniques, the misorientation between the grains of this bicrystal was determined to conform to a so called $\Sigma=5$ pure tilt (36.8° tilt about a common [001] tilt axis) grain boundary. High resolution electron microscopy revealed the boundary to be symmetrical, with a common {310} grain boundary plane.

Self-supported TEM samples were prepared from these specimen by first ultrasonically drilling 3 mm discs. These discs were then mechanically thinned and then dimpled to a thickness of ~10 μm. Lastly, the dimpled discs were milled with Ar$^+$ ions in a Gatan Duomill ion-beam thinner at liquid nitrogen temperature (to reduce ion beam damage) until perforation.

All transmission electron microscopy of the samples was carried out in the Hitachi HF-2000 atomic resolution analytical electron microscope (AR-AEM). This microscope is equipped with a cold field emission gun (cFEG) and can be operated at accelerating voltages of up to 200 kV. The microscope is fitted with an Oxford ultra-thin window energy dispersive X-ray spectrometer for XES acquisition which allows detection of light elements down to carbon. It is also equipped with a Gatan 666 parallel electron energy loss spectrometer (PEELS) for electron energy loss spectra acquisition with an energy resolution of less than 0.5 eV (full width at half maximum for zero loss peak). All EELS spectra were acquired on a Macintosh II fx computer running Gatan EL/P software. In order to reduce the effects of carbon contamination during microanalysis work, a liquid nitrogen TEM specimen holder was employed for all PEELS and XES studies. SIMS experiments were conducted on the University of Chicago SIMS [7].

The spatial resolution, $R$, of the XES experiments was considered. $R$ is limited by the probe size, $d$, of the electron beam impinging on the specimen surface and the beam broadening, $b$, caused by elastically scattered electrons traveling through the sample, and is given by [9]

$$ R = \sqrt{d^2 + b^2}. $$

The probe size, $d$, was estimated to be 2.5 nm at full-
width-at-tenth-maximum (FWTM). The beam broadening, $b$, was estimated using a Monte Carlo simulation program developed by Joy [10]. An EEL low loss spectrum was acquired to calculate the thickness of the sample, which was conservatively estimated at 500 Å. Utilizing the single scattering simulation, a 90% beam broadening estimate of 1.2 nm was obtained for strontium titanate based on the trajectories of 30000 electrons. Based on these estimates, the spatial resolution was calculated to be $\sim 2.8$ nm ($d \approx 2.5$ nm, $b \approx 1.2$ nm).

EELS analysis helps to avoid many of the shortcomings associated with XES studies. The increased intensity of the signal in EELS allows much shorter collection times when compared with XES which helps to reduce contamination problems as well as beam and sample drift during microanalysis. Acquisition times for the individual spectra varied from less than a second for the low loss region up to a maximum of 12.8 s for the core loss region with eight of these spectra acquired sequentially and added to produce a final spectrum. The X-ray emission spectra, on the other hand, took as long as 5-7 min to collect. Also, peak overlap, often a problem for elements of similar atomic number in XES, is avoided in EELS due to superior energy resolution with access to many edges in addition to the standard K and L lines used in XES. Finally, core loss EELS does not suffer from delocalization of the signal (since delocalization is inversely proportional to the energy loss [9]) and hence the spatial resolution is essentially limited by the probe size. The spectra were acquired in the diffraction mode which allows focusing of the transmitted spot on the collection entrance aperture. The collection semi-angle, $\beta$, was 7.5 mrad for all experiments.

3. Results and discussion

3.1. SIMS analysis

The SIMS analysis indicated uniform presence of Sr and Ti throughout most of the sample in both Fe and Fe/Mn doped SrTiO$_3$ as would be expected from the SrTiO$_3$ matrix. However, inhomogeneities are observed in both specimens through the presence of bulk second phase regions. These second phase regions are depleted in Sr in the case Fe/Mn doped specimen, as can be seen from Fig. 1, containing a series of SIMS micrographs of a single 40 × 40 µm$^2$ region. Within these second phase regions, the presence of Fe and Mn is also enhanced, as can be seen from the Fe and Mn ion maps in Fig. 1. Scans from the Fe-doped sample also revealed bulk second phases which are Ti and Fe rich but depleted in Sr.

These second phase regions were encountered in the course of microanalysis work in the TEM studies as well. Fig. 2 shows an X-ray emission spectrum from the Fe/Mn doped sample. The spectrum was collected from the bulk of a second phase grain; it clearly shows Mn enrichment and Sr depletion. Interestingly, there is no evidence of enhanced segregation of Fe or Mn near these second phase regions. XES from grain boundaries adjacent to the Mn rich grains did not show any enhancement of the Mn signal, as one might expect due to the Mn reservoirs offered by the second phase grains. We therefore presume that these second phases are stoichiometric manganese titanate grains, with no excess Mn. The SIMS micrographs in Fig. 1 depict this as well; in the regions immediately about the second phases, there is no indication of increased dopant concentration, either in the bulk or at the grain boundaries.

The origin of these second phases is most definitely due to the ceramic processing techniques employed to fabricate these samples. Inhomogeneities in the starting ball-milled powders could lead to iron rich regions which could form iron titanate compounds. Moreover, the mixing of MnO and SrTiO$_3$ for the second firing treatment could also produce manganese titanate compounds. One would expect these phases to be present near the surfaces of the original sintered ceramics due to bulk diffusion considerations.

In addition to the exposure of second phase regions in the doped strontium titanate bulk samples, the SIMS studies also depicted preferential Mn segregation at the grain boundaries. The Mn ion map in Fig. 3 does show an inhomogeneous distribution of Mn throughout the sample with enrichment at the grain boundaries. Such preferential segregation is to be expected as the grain boundaries offer a rapid diffusion path for the dopant material. Note that the width of the Mn segregation layer is limited to the resolution of the SIMS probe, which is roughly 50 nm.
Aside from the second phase regions, the Mn ion signal is limited to one pixel in width.

The evidence of Fe segregation was not as clearly convincing as that of Mn with the SIMS analysis. The Fe ion map in Fig. 4 hints at a heterogeneous distribution of Fe between the grain bulk and grain boundaries; however, the results are hardly conclusive. The segregation profiles suggested by the SIMS analysis for these acceptor doped samples were at the limits of the SIMS technology and therefore necessitate the use of other analytical techniques for further study.

3.2. XES microanalysis

XES microchemical analysis of the grain boundaries proved challenging due to the small amounts of dopant material added to the material. In all cases, dopant segregation levels fell off to the background levels within 5 to 10 nm from the grain boundaries. There was no evidence of second phases or amorphous phases decorating the grain boundaries in either the Fe-doped or Fe/Mn-doped polycrystalline samples. Grain boundaries chosen for XES profiling were all oriented parallel to the EDS detector. A typ-
Fig. 2. X-ray emission spectrum from a second phase grain in Fe/Mn doped SrTiO$_3$ polycrystal.

Fig. 3. Mn ion SIMS micrographs of the Fe/Mn doped SrTiO$_3$ polycrystal. Grain boundary segregation of Mn is evident in this $10 \times 10 \mu m^2$ region.

Fig. 4. Fe ion SIMS micrograph of the Fe doped SrTiO$_3$ polycrystal.

Fig. 6a shows a composite plot of the Fe/Ti peak intensity ratio for all of the grain boundaries studied in the Fe-doped sample. The horizontal error bars represent the effects of beam broadening as well as an estimated 10% error in probe positioning. The vertical error bars reflect the 90% confidence level for Student $t$-analysis of the data. Peak counts were arrived at by integrating the signal over the full width half maximum (FWHM) region of each peak and then subtracting the background. The background was approximated by summing the counts in the same energy width as the peak FWHM on either side of the peak. There is a clear trend of Fe segregation to the boundaries, although there is a spread in the amounts of segregation seen at individual boundaries. No statistically significant variations in the Ti/Sr (Fig. 6b) peak intensity ratio could be detected between the bulk and the grain boundary.

Similarly for the Fe/Mn doped sample, Mn is confined to the grain boundaries or bulk second phases.

are essentially too low to be detected above background due to the low dopant concentration, despite the fact that the Fe was added as a bulk dopant. Furthermore, the segregation of Fe to the boundaries as well as the presence of Fe rich bulk second phases (as seen with SIMS) would further decrease the concentration of Fe in the bulk of SrTiO$_3$ grains.

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The spectra shown in Fig. 7a and b are typical of the segregation behavior seen for Mn in this sample. Again, the bulk spectra was taken 5 nm away from the interface and the Mn signal has essentially dropped to background levels at this distance. The Ar peak present in this spectra is an artifact from ion beam thinning and was traced to the specific IBT routine used prior to that particular microscopy session.

Again, the composite plots for all the grain boundaries studied in the Fe/Mn doped SrTiO₃ are given in Fig. 8a and b. The results are similar to those obtained for Fe segregation, although the mechanisms involved are different. The Mn segregation is limited to a region within 10 nm of the boundary and the intensity varies slightly from boundary to boundary. Unfortunately, the study of Fe segregation in the Mn/Fe doped samples was hampered by the overlap of the Mn Kβ and Fe Kα peaks. Furthermore, it is likely that Fe X-ray excitations could lead to fluorescence of Mn species thus resulting in enhanced Mn excitations and depleted Fe excitations. Nonetheless, the Fe segregation behavior of the Mn/Fe doped sample is expected to be similar to that detected in the Fe
doped sample as the materials are the same up to the second firing treatment.

The results of the XES profiles across the Mn/Fe doped samples agree well with the suggestion of grain boundary segregation hinted at by SIMS. The agreement with the SIMS experiments indicates that the Mn segregation seen by the AEM microanalysis is not restricted to a few special boundaries, but is indeed a general feature of the sample. The presence of grain boundary segregation of Fe was less convincing from the SIMS analysis than that in the AEM. However, this is likely due to the smaller amounts of Fe segregation, which involves diffusion of Fe ions through the bulk to grain boundaries, than Mn segregation which was carried out via a rapid grain boundary diffusion mechanism.

The effect of a donor dopant was studied by XES in the case of the Nb-doped SrTiO₃ bicrystal. The results of the XES investigation for Nb segregation are not as conclusive as those for acceptor doped solutes. There is a hint of Nb segregation to the grain boundary, in agreement with the findings of Desu and Payne.
[6]; however the limited number of profiles acquired leave the results less conclusive. Spectra were collected from the bulk and the grain boundary using both a spot probe (as with the XES analysis of the acceptor doped SrTiO₃) and also a “line” probe along the grain boundary. The raw spectra collected from the boundary and from the bulk are compared in Fig. 9a and b while the results of the profiles are shown in Fig. 10a and b. The vertical error bars in Fig. 10 are those for a “one σ” (67% confidence level) deviation. The enhancement of the Nb/Ti peak intensity ratio seen to the right of the interface is likely an artifact due to poor alignment of the grain boundary with the detector. The grain boundary was oriented such that it was almost perpendicular to the detector with the spectra composing the right hand side of the plot in Fig. 10 coming from the crystal that was opposite the detector. Consequently, X-rays from this crystal would have traveled through the interface on their way to the detector, leading to enhancement of the Nb signal for this crystal. As with the acceptor-

![Fig. 9](image1)

![Fig. 10](image2)

Fig. 9. (a) X-ray emission spectrum from a grain boundary of the 0.05 wt% Nb doped SrTiO₃ bicrystal; (b) X-ray emission spectrum 5 nm away from the same boundary as of (a).

Fig. 10. (a) Nb/Ti XES segregation profile for the 0.05 wt% Nb doped SrTiO₃ bicrystal. Horizontal error bars include 10% positioning error and beam broadening estimates, while vertical error bars are for a 67% confidence level; (b) Ti/Sr XES segregation profile for the 0.05 wt% Nb doped SrTiO₃ bicrystal. Horizontal error bars include 10% positioning error and beam broadening estimates, while vertical error bars are for a 67% confidence level.
doped samples, there was no evidence of a second phase at the grain boundary in the Nb doped bicrystal.

3.3. EELS microanalysis

To perform core loss EELS, a line probe was positioned along the grain boundary and then stepped away from the interface. The effect of the line probe is to average the signal along the boundary. The results of EELS profiling across the grain boundary of Mn/Fe doped sample are given in Fig. 11. Again, the results of the XES and SIMS studies are confirmed by the spike in the Mn/Ti edge intensity ratio at the interface. The raw spectra (corrected for channel to channel gain variation and dark current) from a grain boundary and from a bulk position 5 nm away from the grain boundary are displayed in Fig. 12. The energy dispersion is 0.3 eV/channel. The presence of the Mn L edge is clearly visible in the grain boundary spectrum; however, it is absent in the bulk spectrum. Note that the Fe edge, which should be found at 708 eV, is not detected either in the bulk or at the boundary. Again, the Fe signal is apparently too weak to be detected above the background of the spectra. Some variation in the Ti L₁ edge and in the Ti L₂,₃ near edge structure is also apparent between the bulk and grain boundary spectra. These variations may be due to local changes in the bonding of Ti at the grain boundaries. Although we have yet to fully explore the nature of these variations, they are indicative of the wealth of information offered by EELS.

4. Conclusions

The results of this study further support the significance of grain boundary segregation in perovskite materials. XES and EELS studies of segregation profiles for Fe and Mn in acceptor-doped strontium titanate polycrystals show a pronounced segregation to the grain boundaries with very steep gradients away from the boundary. Fe and Mn segregation is limited to within a 5 nm distance about the boundary, or to the limits of step size in this experiment, without the presence of any second phases at the boundary. Moreover, XES studies do not indicate any host cation non-stoichiometry at the interface. The generality of the XES and EELS segregation profiles is confirmed by SIMS analysis of the acceptor doped samples which indicated Mn segregation to the grain boundaries and hint at Fe segregation as well. The chemical microanalysis of the interfaces of donor-doped SrTiO₃ shows slight segregation of the Nb donor dopant species for a lightly doped (0.5 wt%) strontium titanate bicrystal. Such measurements demonstrated the utility of applying a battery of microanalytic techniques in studying relevant materials.
issues and the consistency of the results presents a coherent picture of the nature of the grain boundaries in doped strontium titanate.

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